

**ISP626-1X, ISP626-2X, ISP626-4X
ISP626-1, ISP626-2, ISP626-4**



**LOW INPUT CURRENT A.C. INPUT
PHOTOTRANSISTOR OPTICALLY
COUPLED ISOLATORS**

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 approval pending
- ISP626-1X - Certified to EN60950 by the following Test Bodies :-
 - Nemko - Certificate No. P96102022
 - Fimko - Registration No. 192313-01..25
 - Semko - Reference No. 9639052 01
 - Demko - Reference No. 305969
 ISP626-2X, ISP626-4X - EN60950 pending

DESCRIPTION

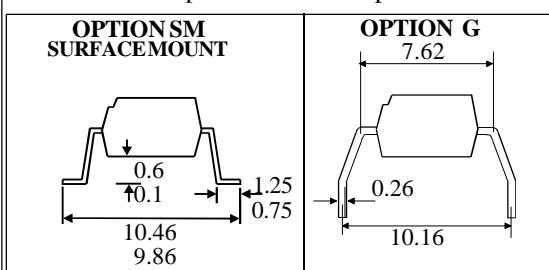
The ISP626-1, ISP626-2, ISP626-4 series of optically coupled isolators consist of two infrared light emitting diodes connected in inverse parallel and NPN silicon photo transistors in space efficient dual in line plastic packages.

FEATURES

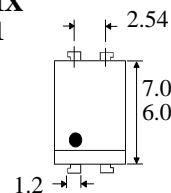
- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- Low input current $\pm 0.5\text{mA}$ I_F
- High Isolation Voltage ($5.3\text{kV}_{\text{RMS}}, 7.5\text{kV}_{\text{PK}}$)
- AC or polarity insensitive input
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

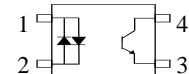
- Computer terminals
- Industrial systems controllers
- Telephone sets, Telephone exchangers
- Signal transmission between systems of different potentials and impedances



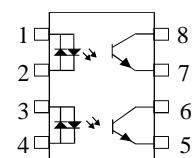
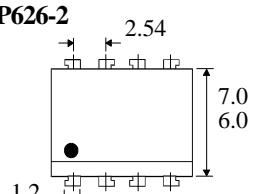
**ISP626-1X
ISP626-1**



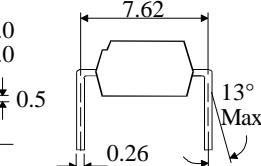
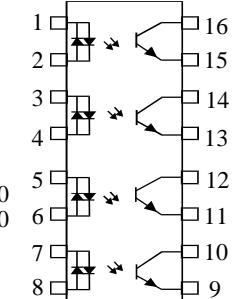
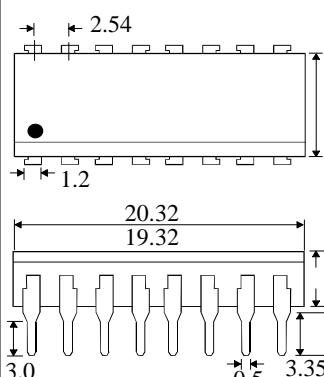
Dimensions in mm



**ISP626-2X
ISP626-2**



**ISP626-4X
ISP626-4**



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	\pm 50mA
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	55V
Emitter-collector Voltage BV_{ECO}	6V
Power Dissipation	150mW

POWER DISSIPATION

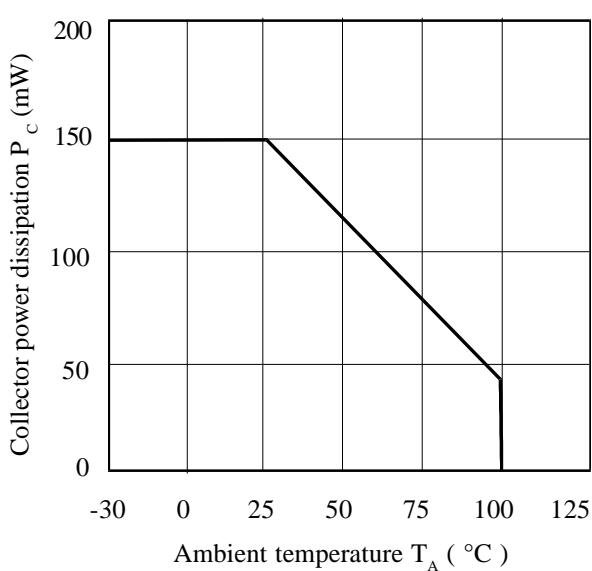
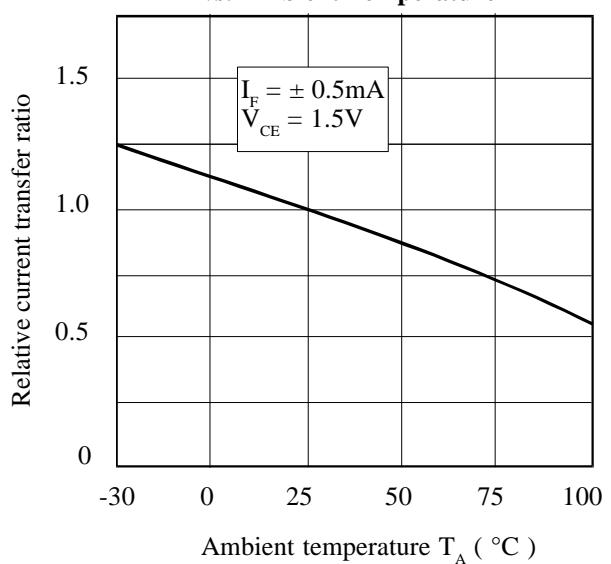
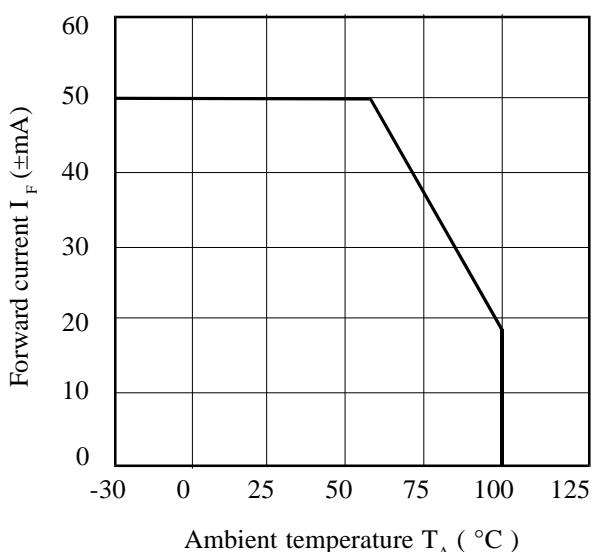
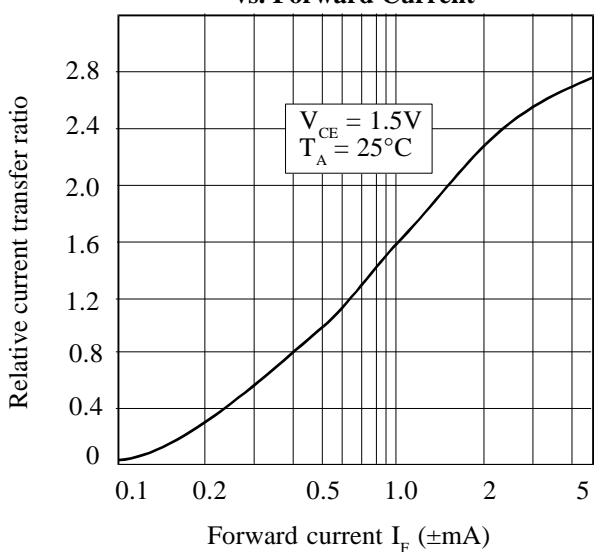
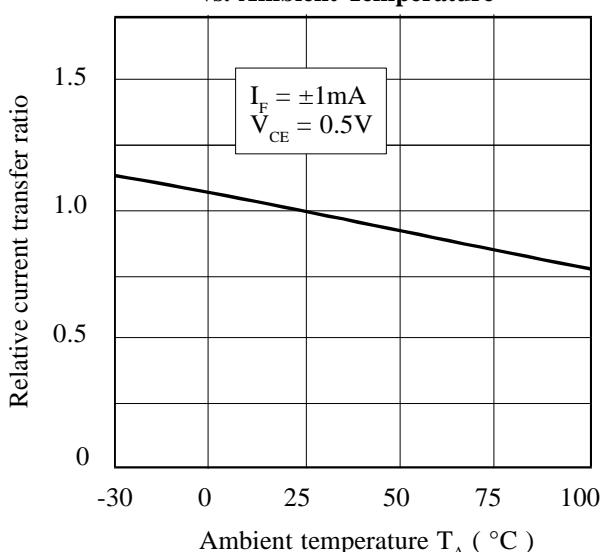
Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)	1.0	1.15	1.3	V	$I_F = \pm 10\text{mA}$
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	55			V	$I_C = 0.5\text{mA}$
	Emitter-collector Breakdown (BV_{ECO})	6		100	V nA	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current (I_{CEO})					$V_{CE} = 24\text{V}$
Coupled	Current Transfer Ratio (CTR) (Note 2) Low Input CTR	100 50		1200	% %	$\pm 1\text{mA}I_F, 0.5\text{V } V_{CE}$ $\pm 0.5\text{mA}I_F, 1.5\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$		0.2	0.4	V V	$\pm 1\text{mA}I_F, 0.5\text{mA}I_C$ $\pm 1\text{mA}I_F, 1\text{mA}I_C$
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Rise Time tr		8		μs	$V_{CC} = 10\text{V},$
	Fall Time tf		8		μs	$I_C = 2\text{mA}, R_L = 100\Omega$
	Turn-on Time ton		10		μs	
	Turn-off Time $toff$		8		μs	

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

Collector Power Dissipation vs. Ambient Temperature**Relative Current Transfer Ratio vs. Ambient Temperature****Forward Current vs. Ambient Temperature****Relative Current Transfer Ratio vs. Forward Current****Relative Current Transfer Ratio vs. Ambient Temperature****Relative Current Transfer Ratio vs. Forward Current**